

Syllabus - Physics 461 - 2008

Instructor: Gary Farlow  
271 Fawcett Hall  
775 - 3340  
Office hours Wednesday 2:30-4:30, or by appointment

Text: Omar: **Elementary Solid State Physics**. 2<sup>nd</sup> edition

Supplements: Myers, **Introductory Solid State Physics**  
Hook and Hall, **Solid State Physics**, 2<sup>nd</sup> edition  
Kittel, **Introduction to Solid State Physics**, 8<sup>th</sup>  
edition.  
Ashcroft and Mermin, **Solid State Physics**

Grades: Midterm - 25%  
Final - 25% This will be a paper on a modern solid  
state topic of interest to you. The topic and scope  
will need to be arranged by the 2<sup>nd</sup> week of the  
quarter  
Homework -25% Due Tuesday of each week!  
Lab - 25%

Labs: Begin first week. Need one hour introductory session for  
each lab then you are on your own to get them done. Allow two  
weeks and 7 hours per lab. Labs will be set out in RM 219  
Fawcett

Debye-Sherer - X-ray crystallography  
Laue - X-ray crystallography  
Hall measurements  
Debye temperature measurements  
Optical absorption measurements

Homework:	Classwork:
Crystallography 1: 2,4,10,11,14, also find the compressibility in problem 14	1: 1,3,5,6,8,11,13
X-ray diffraction 2: 2,4,13,20,25	2: 3,9,14,15,17,21

<p>Point defects  11: 1,3,6,7 (look at question 5),  a) Use defect distribution generated by TRIM for 1MeV AR on 1 micron film of AgBr to calculate the average number of number of Frenkel pairs  (b) The formation energy and migration energies for AgBr are given at the right. Compute the Ionic cond. in AgBr at 100C both with and without the radiation damage of the previous problem.</p>	<p>11: 4,5,19  Formation energy for AgCl  <math>H_F = 1.134 \text{ eV}</math>    <math>S_F = 6.55 k_b</math>  Migration energies  <math>H_{vac} = 0.325 \text{ eV}</math>    <math>s_{vac} = 1.16 k_b</math>  <math>H_i = 0.043 \text{ eV}</math>    <math>s_i = -3.18 k_b</math>  <math>H_{stlcy} = 0.278 \text{ eV}</math>    <math>S_{stlcy} = 1.35 k_b</math>  Aboage &amp; Friauf Phys. Rev. B, 11, 1654 (1975).</p>
<p>Vibrational/thermal properties  3: 1,4(at high temp.),6,13,16</p>	<p>3: 5,8,15,lagrange method</p>
<p>Free electron metals  4: 1,7,10,12 (use log-log plots),15</p>	<p>4: 3,4,6,11,13</p>
<p>EXAM chapters 1-4,11</p>	<p>Take home due Feb 14 at 9:00 am</p>
<p>Real metals/band structure  5: 7,9,14,17,21 (it is the current density transverse to the field that must be zero)</p>	<p>5: 11,12,15,18,19</p>
<p>Semiconductors (2 weeks)  6: 2,4,5,6,9  6: 14,16,17,19,20</p>	<p>6: 3,7,10,11,13,15,18,</p>
<p>Magnetism  9: 4,6,11,12,19</p>	<p>9: 5,13,14,16,17</p>
<p>Superconductivity (if we get there)  10:1, 3, 5, 8, 9,</p>	<p>10: 2,4,6,7,</p>
<p>Final Exam - paper on special topic.</p>	<p>Due at the time of the scheduled exam.</p>